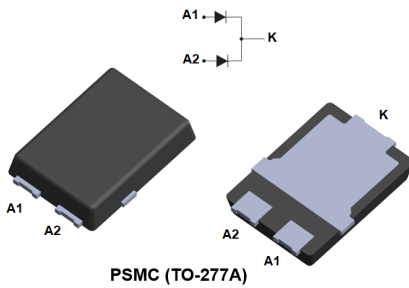



Automotive 200 V, dual 5 A ultrafast rectifier



Features

- AEC-Q101 qualified 
- PPAP capable
- 175 °C maximum operation junction temperature
- V_{RRM} guaranteed from -40 °C to 175 °C
- High surge current capability
- ECOPACK2 compliant component

Application

- Reverse polarity protection in E.C.U
- DC/DC converters
- Freewheeling diodes
- LED Lighting

Description

The STTH1002CSFY has been developed for applications requiring an optimized V_F and reverse recovery characteristics.

These characteristics make it ideal for use in secondary rectification functions, such as DC/DC converters or lighting applications.

Product status link	
STTH1002CSFY	
Product summary	
Symbol	Value
$I_{F(AV)}$	2 X 5 A
V_{RRM}	200 V
$t_{rr(max)}$	27 ns
$T_j(max.)$	175 °C
$V_F(typ.)$	0.79 V

1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified, per diode)

Symbol	Parameter		Value	Unit	
V_{RRM}	Repetitive peak reverse voltage ($T_j = -40\text{ °C}$ to $+175\text{ °C}$)		200	V	
$I_{F(AV)}$	Average forward current, $\delta = 0.5$	Per diode	$T_c = 160\text{ °C}$	5	A
		Per device	$T_c = 160\text{ °C}$	10	
I_{FSM}	Surge non repetitive forward current		$t_p = 10\text{ ms}$ sinusoidal	85	A
T_{stg}	Storage temperature range		-65 to +175	°C	
T_j	Operating junction temperature range		-40 to +175	°C	

Table 2. Thermal resistance parameters

Symbol	Parameter		Typ.	Unit
$R_{th(j-c)}$	Junction to case	Per diode	2.45	°C/W
		Per device	1.66	
$R_{th(c)}$	Coupling		0.87	°C/W

For more information, please refer to the following application note:

- AN5088: Rectifiers thermal management, handling and mounting recommendations

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode1}) = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$	-		4	μA
		$T_j = 125\text{ °C}$		-	4	40	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 5\text{ A}$	-	0.91	1.05	V
		$T_j = 125\text{ °C}$		-	0.79	0.91	
		$T_j = 25\text{ °C}$	$I_F = 10\text{ A}$	-	1.02	1.17	
		$T_j = 125\text{ °C}$		-	0.90	1.04	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$

2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.78 \times I_{F(AV)} + 0.026 \times I_{F(RMS)}^2$$

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses in a power diode

Table 4. Dynamic characteristics per diode at $T_j = 25^\circ\text{C}$, unless otherwise specified

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$T_j = 25^\circ\text{C}$	$I_F = 1\text{ A}$, $di_F/dt = -50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	28	35	ns
			$I_F = 1\text{ A}$, $di_F/dt = -100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	21	27	
I_{RM}	Reverse recovery current	$T_j = 125^\circ\text{C}$	$I_F = 5\text{ A}$, $di_F/dt = -200\text{ A}/\mu\text{s}$, $V_R = 160\text{ V}$	-	6.3		A

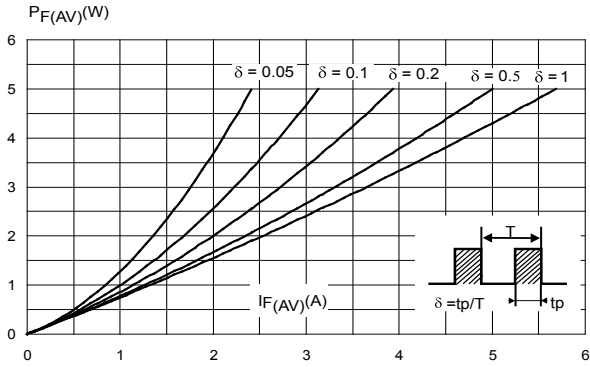
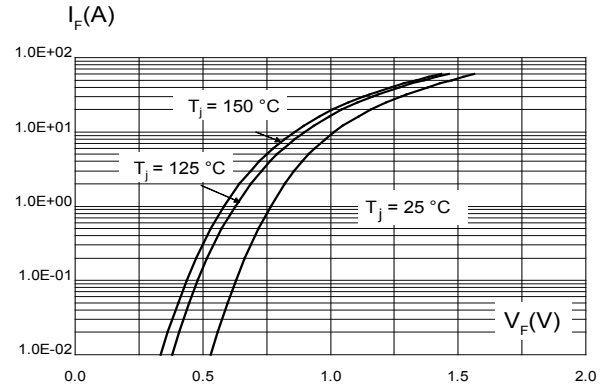
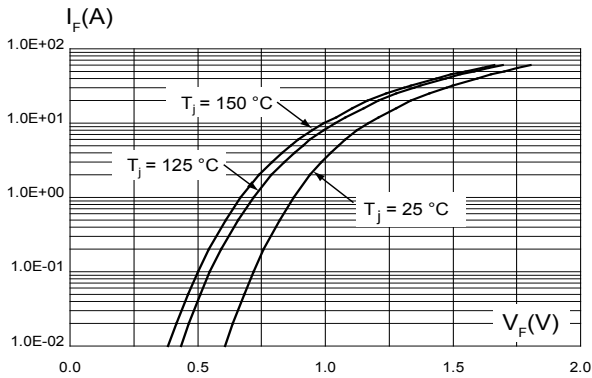
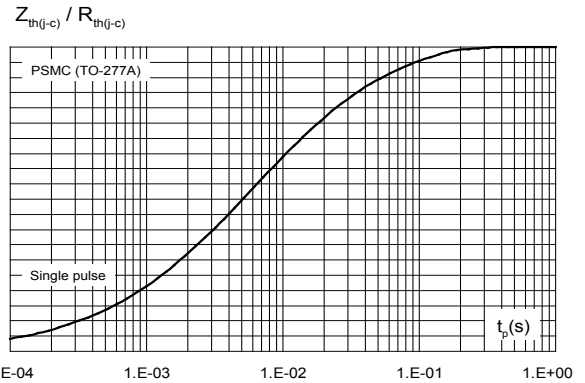
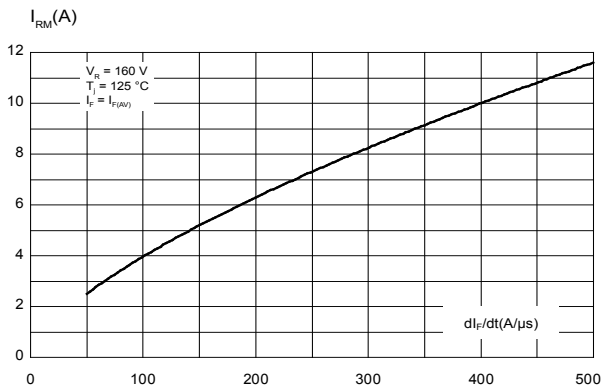
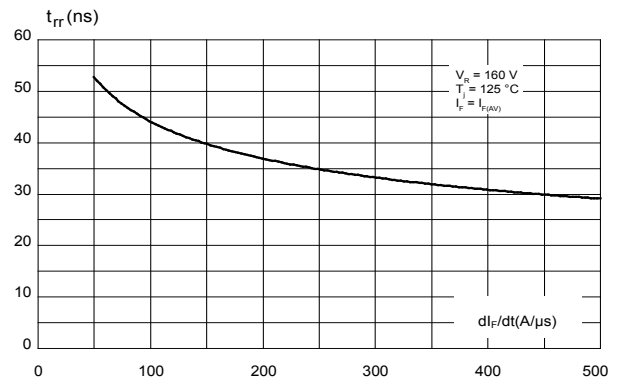
1.1 Characteristics (curves)
Figure 1. Conduction losses versus average forward current (per diode)

Figure 2. Forward voltage drop versus forward current (typical values, per diode)

Figure 3. Forward voltage drop versus forward current (maximum values, per diode)

Figure 4. Relative variation of thermal impedance junction to case total versus pulse duration

Figure 5. Peak reverse recovery current versus dI_F/dt (typical values, per diode)

Figure 6. Reverse recovery time versus dI_F/dt (typical values, per diode)


Figure 7. Reverse recovery charges versus di_F/dt (typical values, per diode)

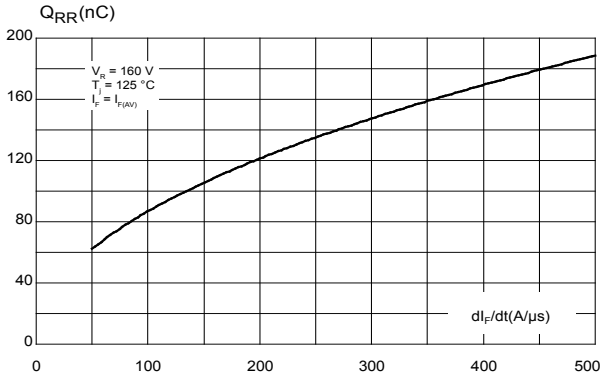


Figure 8. Reverse recovery softness versus di_F/dt (typical values, per diode)

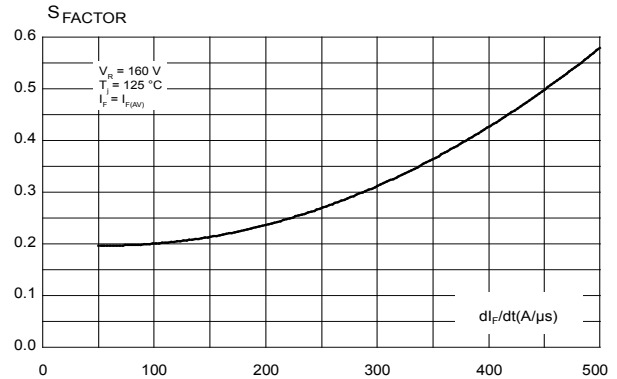


Figure 9. Relative variations of dynamic parameters versus junction temperature

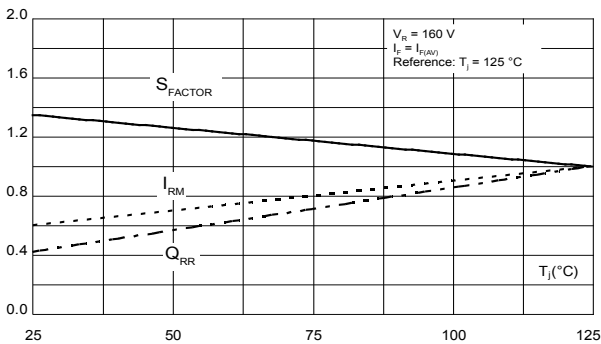


Figure 10. Junction capacitance versus reverse voltage applied (typical values, per diode)

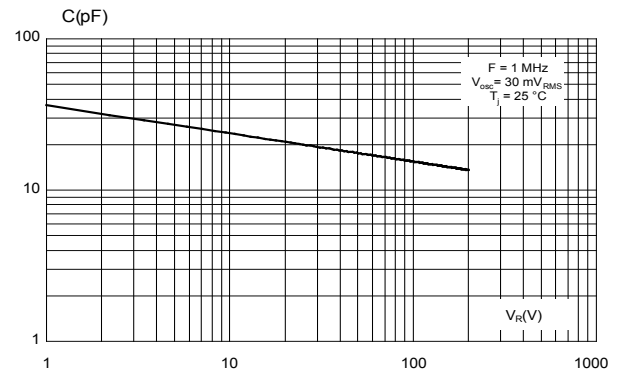
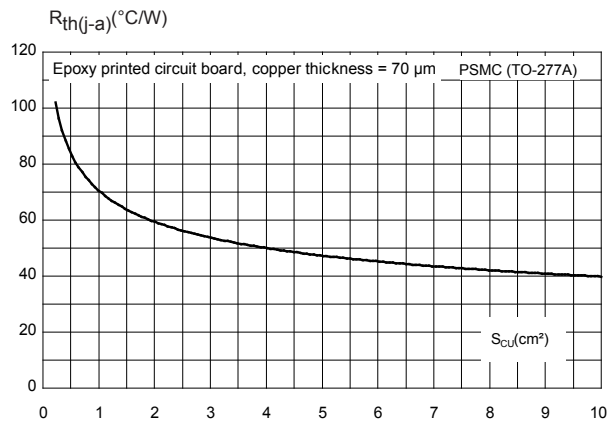


Figure 11. Thermal resistance junction to ambient versus copper surface under tab (typical values, epoxy printed board FR4, $\epsilon_{Cu} = 70 \mu\text{m}$) (PSMC (TO-277A))



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 PSMC (TO-277A) package information

- Epoxy meets UL94,V0
- Cooling method : by conduction (C)

Figure 12. PSMC (TO-277A) package outline

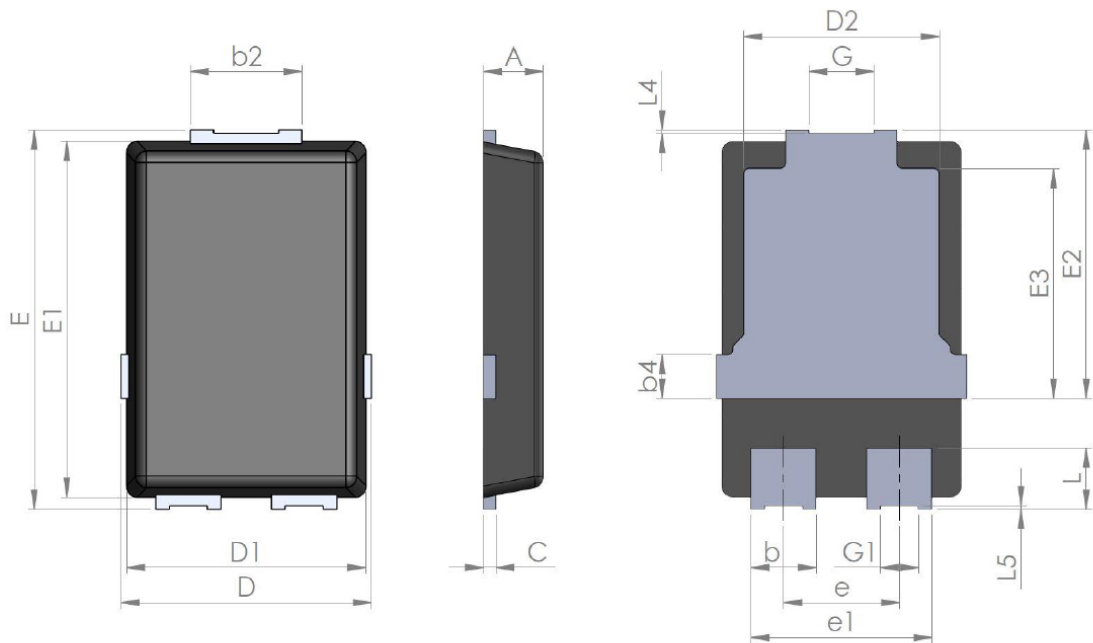
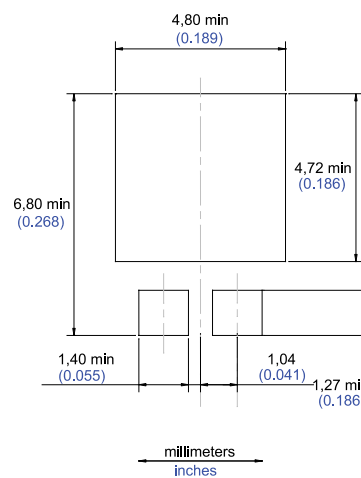


Table 5. PSMC (TO-277A) package mechanical data

Ref.	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.00	1.10	1.20	0.039	0.043	0.047
b	1.05	1.20	1.35	0.041	0.047	0.053
b2	1.90	2.05	2.20	0.075	0.081	0.087
b4		0.75			0.029	
C	0.15	0.23	0.40	0.006	0.009	0.016
D	4.45	4.60	4.75	0.175	0.181	0.187
D1	4.25	4.40	4.45	0.167	0.173	0.175
D2	3.40	3.60	3.70	0.134	0.142	0.146
E	6.35	6.50	6.65	0.250	0.256	0.262
E1	6.05	6.10	6.15	0.238	0.240	0.242
E2	4.50	4.60	4.70	0.177	0.181	0.185
E3		3.94			1.55	
e		2.13			0.084	
e1		3.33			0.131	
G		1.20			0.047	
G1		0.70			0.027	
L	0.90	1.05	1.24	0.035	0.041	0.049
L4	0.02			0.0008		
L5	0.02			0.0008		

Figure 13. PSMC (TO-277A) package footprint in mm (in inches)



Note: For package and tape orientation, reel and inner box dimensions and tape outline please check [TN1173](#)

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH1002CSFY	T1002CY	PSMC (TO-277A)	90 mg	6000	Tape and Reel

Revision history

Table 7. Document revision history

Date	Version	Changes
29-Oct-2020	1	Initial release.

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